

## FEATURES

- Glass passivated junction
- High current diverting capability 250A
- Low capacitance, less than 200pF
- UL recognized
- Automatic reset
- Does not degrade

## APPLICATION

- Bi-directional device for telephone and line card protection

## ELECTRICAL CHARACTERISTICS (Tamb = +25°C)

SYMBOL	PARAMETER
V <sub>RM</sub>	Stand-off Voltage
V <sub>BR</sub>	Breakdown Voltage
I <sub>H</sub>	Holding Current
V <sub>R</sub>	Continuous Reverse Voltage

## ABSOLUTE RATINGS (limiting values) (T<sub>j</sub> = + 25°C) L = 10mm

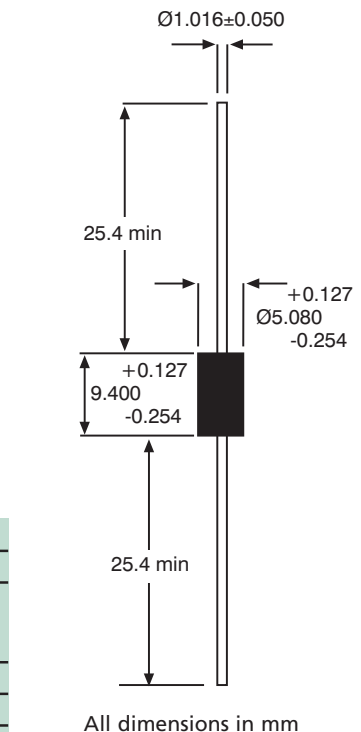
SYMBOL	PARAMETER	VALUE	UNIT
P	Power dissipation on infinite heatsink Tamb = 50°C	5	W
I <sub>pp</sub>	Peak Pulse Current 10x1000µsec 10/700 1.5KV 8-20 us expo	100 125 250	A
I <sub>tsm</sub>	Non-repetitive surge peak on-state current tp = 20 ms	50	A
di/dt	Critical rate of rise of on-state current Non repetitive	100	A/us
T <sub>stg</sub> T <sub>j</sub>	Storage and operating junction Temperature range	-40 to 150 150	°C °C
T <sub>l</sub>	Maximum lead temperature for soldering during 10s at 4mm from case	230	°C

## THERMAL RESISTANCES

SYMBOL	PARAMETER	VALUE	UNIT
R <sub>th(j-i)</sub>	Junction-leads on infinite heatsink L = 10mm	20	°C/W
R <sub>th(j-a)</sub>	Junction-ambient on printed circuit	75	°C/W

All parameters are tested using Fet Test™ Model 3600

DEVICE TYPE	I <sub>RM</sub> @ V <sub>RM</sub> max		I <sub>R</sub> @ V <sub>R</sub> max		V <sub>BO</sub> @ I <sub>BO</sub> max		I <sub>H</sub> min	C typ
	µA	V	µA	V	V	mA		
T10B035	2	32	50	35	55	800	150	180
T10B065	2	55	50	65	80	800	150	160
T10B120	2	110	50	120	160	800	150	140
T10B140	2	120	50	140	200	800	150	140
T10B200	2	170	50	200	265	800	150	130
T10B230	2	200	50	230	300	800	150	120
T10B270	2	230	50	270	350	800	150	120



## ORDERING INFORMATION

T10B □□□□□□□□

Voltage ———

Holding Current Option ———

Packaging Option ———

B = Bulk (500 pcs)  
T = Tape and reeled (1500 pcs)